MIP517

Silicon MOSFET type integrated circuit

■ Features

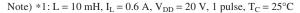
- Built-in five protection functions. (over-current, over-voltage, loadshort-circuit, over heat, ESD)
- Driving directly from CMOS (microcomputer) is possible.
- Although it is a small package, it has resistance of low heat. (When mounted in a substrate.)

Applications

- Lamp-Solenoid, driver
- Motor driver

■ Absolute Maximum Ratings $T_C = 25^{\circ}C \pm 3^{\circ}C$

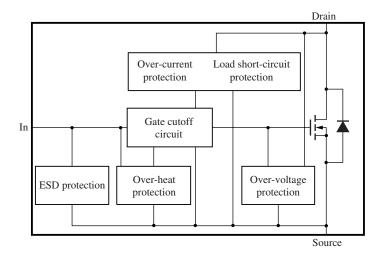
Parameter	Symbol	Rating	Unit
Drain-source voltage	V _{DS}	- 0.5 to +45	V
Output current	I _O	0.7	A
Input voltage	V _{IN}	- 0.5 to +6.0	V
Input current	I_{IN}	±2	mA
Drain clamp energy endurance *1	E _{CLP}	1.8	mJ
Power dissipation 1 *2	P_{D1}	0.2	W
Power dissipation 2 *3	P_{D2}	0.8	W
Operating ambient temperature	T _{opr}	-40 to +85	°C
Channel temperature	T _{ch}	150	°C
Storage temperature	T_{stg}	-55 to +150	°C



- *2: Single unit
- *3: Mounting on the PCB (40 mm², thickness 1.7mm glass epoxy substrate) ($T_a = 25$ °C)

Marking Symbol: MC

■ Block Diagram



■ Electrical Characteristics $T_C = 25$ ° $C \pm 3$ °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source ON resistance	R _{DS(on)}	$V_{IN} = 5 \text{ V}, I_{DS} = 0.5 \text{ A}$		1.1	1.65	Ω
Drain-source voltage	V _{DS(on)}	$V_{IN} = 5 \text{ V}, I_{DS} = 0.5 \text{ A}$		1.1	1.65	V
Drain clamp voltage	V _{DS(CLP)}	$V_{IN} = 0 \text{ V}, I_{DS} = 3 \text{ mA}$	45	52		V
Drain-source cutoff current 1	I _{DS(off)1}	$V_{IN} = 0 \text{ V}, V_{DS} = 12 \text{ V}$		0.01	5	μΑ
Drain-source cutoff current 2	I _{DS(off)2}	$V_{IN} = 0 \text{ V}, V_{DS} = 25 \text{ V}$		0.02	8	
Drain-source cutoff current 3	I _{DS(off)3}	$V_{IN} = 0 \text{ V}, V_{DS} = 40 \text{ V}$		0.08	10	
Input voltage high-level	V _{IN(H)}	$I_{DS} = 0.5 \text{ A}$	4			V
Input voltage low-level	V _{IN(L)}	$I_{DS} = 1 \text{ mA}$			0.8	V
Input current (normal)	I _{IN(on)}	$V_{IN} = 5 \text{ V}, V_{DS} = 0 \text{ V}$		0.2	0.5	mA
Input current (act on protection) *	I _{IN(PROT)}	$V_{IN} = 5 \text{ V}$		0.75	1.10	mA
Over current protection limit	I _{OCP}	$V_{IN} = 5 \text{ V}$	0.7	1.1		A
Short circuit load protection limit	V _{DS(SHT)}	$V_{IN} = 5 \text{ V}$	1.0	1.6		V
Input voltage of act on protection	V _{IN(PROT)}		4.0	5.0		V

- Note) 1. At on-state when drain voltage exceeds the "Short circuit load protection voltage", output current begin to oscillate.
 - 2. When drain voltage exceeds the "drain clamp voltage" output MOS turn on, so drain voltage are clamped before the drain-source junction become breakdown
 - 3. *: State of short circuit laod protection and over heat protection (designed guarantee).

■ Electrical Characteristics (Reference value: Non guarantee value)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Cutoff temperature at overheat	T_{SHD}	$V_{IN} = 5 V$		140		°C
Turn-on time	t _{ON}	$V_{DD} = 30 \text{ V}, R_L = 60 \Omega$		3		μs
Turn-off time	t _{OFF}	$I_{DS} = 0.5 \text{ A}, V_{IN} = 5 \text{ V}$		7		

Note) If the chip temperature exceeds the "over heat protection temperature", output current is shut down. And if the chip cool down, the protection will operate automatically again.

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